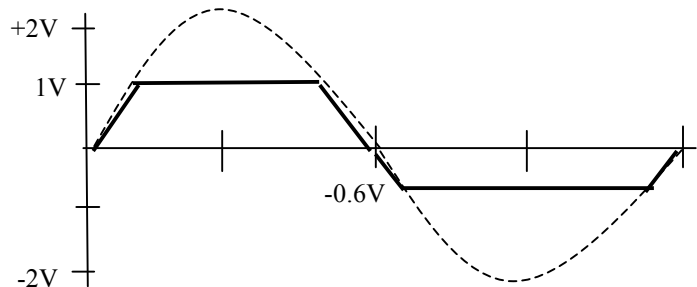
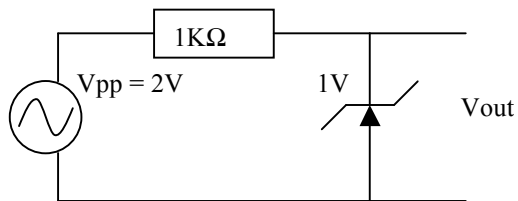
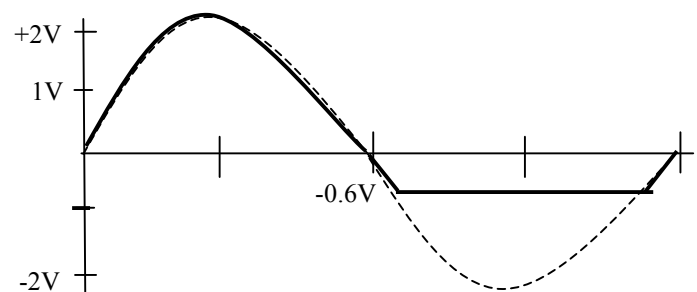
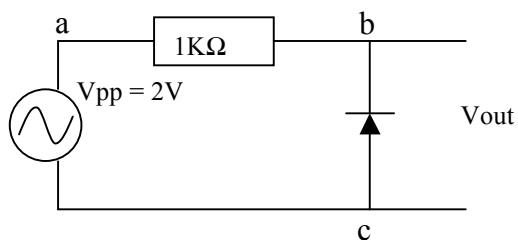


*Read each problem carefully. Show your work for full credit. Place a box around your final answer(s).*

**#1-** Intrinsic semiconductors like Silicon-14 or Germanium-32 are doped with p or n type dopants. Identify the dopants and semiconductors below with a check.

| Element          | Electron Structure                                   | n-type | p-type | Intrinsic |
|------------------|--|--------|--------|-----------|
| B <sub>5</sub>   | (He)2s <sup>2</sup> 2p <sup>1</sup>                  |        | x      |           |
| Al <sub>13</sub> | (Ne)3s <sup>2</sup> 3p <sup>1</sup>                  |        | x      |           |
| Si <sub>14</sub> | (Ne)3s <sup>2</sup> 3p <sup>2</sup>                  |        |        | x         |
| P <sub>15</sub>  | (Ne)3s <sup>2</sup> 3p <sup>3</sup>                  | x      |        |           |
| Ga <sub>31</sub> | (Ar)3d <sup>10</sup> 4s <sup>2</sup> 4p <sup>1</sup> |        | x      |           |
| Ge <sub>32</sub> | (Ar)3d <sup>10</sup> 4s <sup>2</sup> 4p <sup>2</sup> |        |        | x         |
| As <sub>33</sub> | (Ar)3d <sup>10</sup> 4s <sup>2</sup> 4p <sup>3</sup> | x      |        |           |
| In <sub>49</sub> | (Kr)4d <sup>10</sup> 5s <sup>2</sup> 5p <sup>1</sup> |        | x      |           |

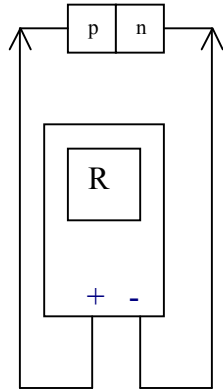
**#2-** A 2Vpp sine wave (dotted line ) is applied to the diode circuits. Sketch Vout for the circuits through one sine-wave cycle. Label the voltage levels carefully.



**Case-1:** The diode is reversed biased on the 1<sup>st</sup> half-cycle and has infinite resistance. All voltage is dropped across it, implying no current flow,  $V_{ac} = V_b$ . On the negative voltage down cycle the same occurs until the voltage  $V_{bc} \sim -0.6V$  and the resistance across the diode drops to zero.  $V_{bc}$  remains at  $-0.6V$ .

**Case-2:** The Zener diode is reversed biased on the positive half-cycle, holding  $V_{bc}$  to a maximum of 1V. On the negative cycle the Zener acts as a normal diode (similar to case-1) following the supply voltage until  $V_{bc} = -0.6V$ .

#3-



In this configuration the resistance meter reads a **HIGH** or **LOW** resistance for the diode? Explain.

LOW - The diode is forward biased so a small resistance to current flow!

#4- An amplifier has a common mode rejection ratio of  $\text{cmrr}=60\text{db}$  and a gain of  $A_v=150$ . If a differential signal of  $2\text{mV}$  is applied to the input along with an unwanted common mode noise of  $10\text{mV}$ , what is the amplitude of the signal and noise at the output?

S = \_\_\_\_\_

N = \_\_\_\_\_

$$60\text{db}=10^3$$

$$A_v = 150 \text{ for true signal } V_{\text{signal}} = 2\text{mV} \times 150 = \mathbf{300\text{mV}_p \text{ or } 600\text{mV}_{pp}}$$

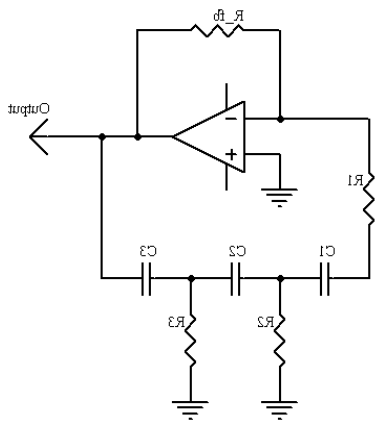
$$A_v = 150 / 10^3 \text{ for common mode noise } V_{\text{noise}} = (10+10)\text{mV} \times 150 \times 10^{-3} = \mathbf{3.0\text{mV}_{pp}}$$

$$\sim 10\text{mV} \times 150 \times 10^{-3} = \mathbf{1.5\text{mV}_p}$$

#5- What is the frequency of the phase shift oscillator shown below. Given  $R_1=R_2=R_3=1\text{k}\Omega$  and  $C_1=C_2=C_3=10\text{pf}$ . Also give  $R_{fb}$ .

$$f = \underline{\hspace{2cm}}$$

$$R_{fb} = \underline{\hspace{2cm}}$$

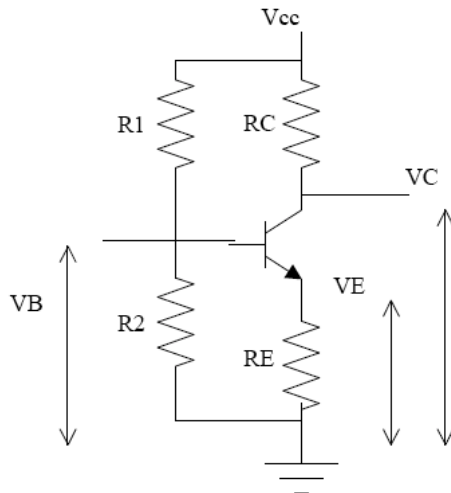


$$f = 1/2\pi RC\sqrt{6} = 6.5\text{MHz}$$

$$R_{fb} = 30R = 30\text{k}\Omega$$

#6- Design a common emitter transistor amplifier with gain of -100 and input impedance of  $12\text{K}\Omega$  using an npn transistor  $\beta = 100$ . Place your resistor parameters in the boxes.

| Vcc  | RC | RE | R1 | R2 |
|------|----|----|----|----|
| +24V |    |    |    |    |



Vcc = +24 V Choose VC = midrange = 12V

$$R_{in} = 12\text{K} = \beta R_E \rightarrow R_E = 120\Omega$$

$$\text{Gain} = -R_C/R_E \rightarrow R_C = 12\text{K}\Omega$$

$$I_C = (V_{cc} - V_C)/R_C = (24 - 12)/12\text{K} = 1.0\text{ mA}$$

$$\text{Let } R_2 = 10 R_E = 1200\Omega$$

$$V_E = I_E R_E \sim I_C R_E = (1.0\text{ mA})(120\Omega) = 0.12\text{ V}$$

$$V_B = V_E + 0.6\text{ V} = 0.72\text{ V}$$

$$V_B = V_{cc} [R_2/(R_1 + R_2)] \text{ or } R_1 + R_2 = R_2/(V_B/V_{cc})$$

$$R_1 = R_2/(V_B/V_{cc}) - R_2 \sim (24 / 0.72)R_2 = 40\text{k}\Omega$$

OR

$$I_2 = V_B/R_2 = (0.72\text{ V}/1200\Omega) = 0.0006\text{ A}$$

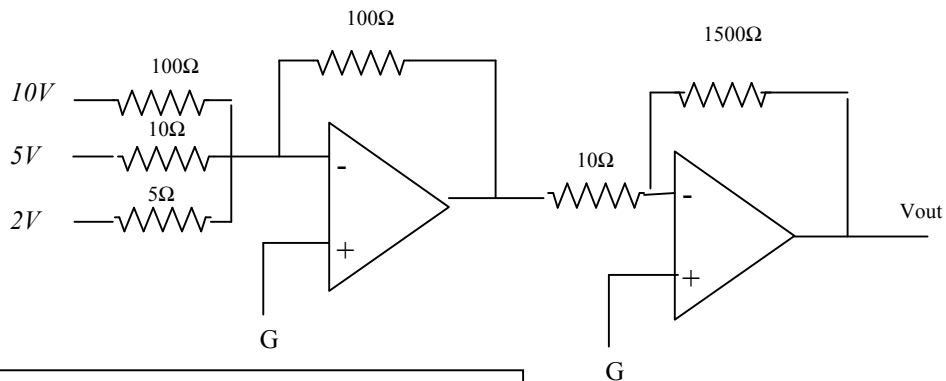
$$I_B = I_C/\beta = (1\text{ mA}/100) = 1\text{e-}5\text{ A}$$

$$I_1 = I_B + I_2 = (1\text{e-}5 + 0.0006)\text{ A} = 0.00061\text{ A}$$

$$R_1 = (V_{cc} - V_B)/I_1 = (24 - 0.72)/0.00061\text{ A} \sim 40\text{k}\Omega$$

#7- What is the output voltage of this OP-AMP circuit?

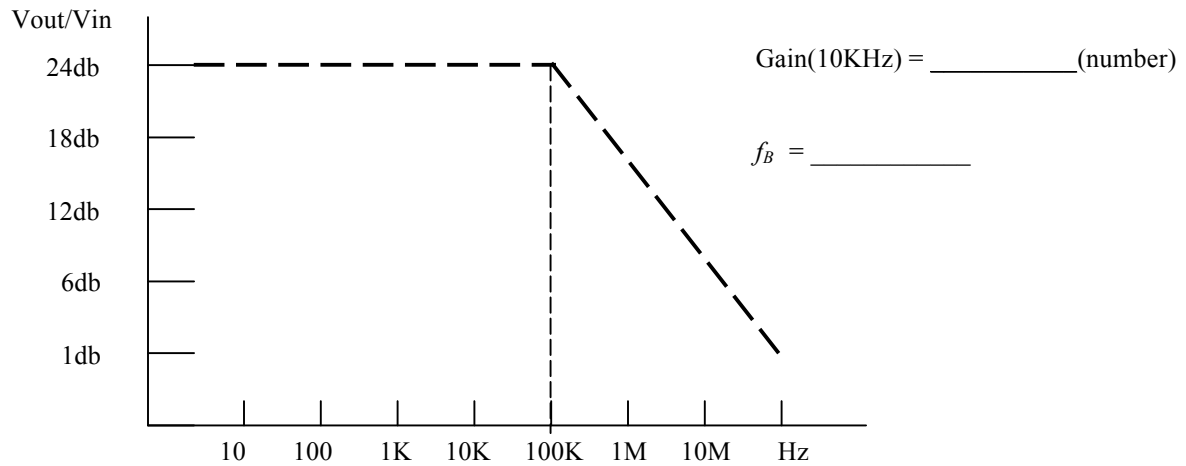
Vout = \_\_\_\_\_



$$V_1 = -10(100/100) - 5(100/10) - 2(100/5) = -100\text{ V}$$

$$V_{out} = -(-100\text{ V})(-1500/10) = 15000\text{ V}$$

#8- The gain versus frequency of an amplifier is shown below. What is the gain of this amplifier at  $f = 10\text{KHz}$ ? What is the break frequency  $f_B$  of the amplifier?



$$24 \text{ db} = 20 \log(V_{out}/V_{in})$$

$$\text{gain} = V_{out}/V_{in} = 10^{(24/20)} = 10^{1.2} = \mathbf{15.8}$$

$f_b$  = frequency when gain drops by a factor of 2 or -6db.

$$\text{db} = 20\log(\text{gain}/2) = \mathbf{17.9 \text{ db}} \rightarrow \mathbf{f_b \sim 800\text{kHz}-1\text{MHz}}$$